# NSN 5961-01-203-5796

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**Inclosure Material:** 

Metal

Internal Configuration:

Junction contact

## Mounting Method:

Terminal

## Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

0.9 base to emitter voltage, dc

#### **Special Features:**

Junction pattern arrangement: npn

#### Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

No

## Fiig:

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